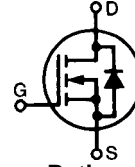


HiPerFET™ Power MOSFETs

N-Channel Enhancement Mode
High dv/dt, Low t_{rr} , HDMOS™ Family

Obsolete:
IXFM10N100
IXFM12N100

~~IXFH/IXFM10N100~~
~~IXFH/IXFM12N100~~
IXFH13N100

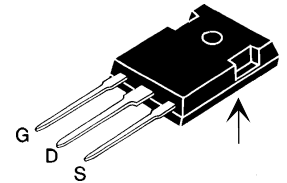


| V_{DSS} | I_{D25} | $R_{DS(on)}$ |
|-----------|-----------|---------------|
| 1000 V | 10 A | 1.20 Ω |
| 1000 V | 12 A | 1.05 Ω |
| 1000 V | 12.5 A | 0.90 Ω |

$t_{rr} \leq 250$ ns

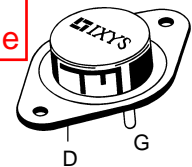
| Symbol | Test Conditions | Maximum Ratings | |
|-----------|--|-----------------------------|------------------|
| V_{DSS} | $T_J = 25^\circ\text{C}$ to 150°C | 1000 | V |
| V_{DGR} | $T_J = 25^\circ\text{C}$ to 150°C ; $R_{GS} = 1$ M Ω | 1000 | V |
| V_{GS} | Continuous | ± 20 | V |
| V_{GSM} | Transient | ± 30 | V |
| I_{D25} | $T_C = 25^\circ\text{C}$ | 10N100 | 10 A |
| | | 12N100 | 12 A |
| | | 13N100 | 12.5 A |
| I_{DM} | $T_C = 25^\circ\text{C}$, pulse width limited by T_{JM} | 10N100 | 40 A |
| | | 12N100 | 48 A |
| | | 13N100 | 50 A |
| I_{AR} | $T_C = 25^\circ\text{C}$ | 10N100 | 10 A |
| | | 12N100 | 12 A |
| | | 13N100 | 12.5 A |
| E_{AR} | $T_C = 25^\circ\text{C}$ | 30 | mJ |
| dv/dt | $I_S \leq I_{DM}$, $di/dt \leq 100$ A/ μs , $V_{DD} \leq V_{DSS}$, $T_J \leq 150^\circ\text{C}$, $R_G = 2$ Ω | 5 | V/ns |
| P_D | $T_C = 25^\circ\text{C}$ | 300 | W |
| T_J | | -55 ... +150 | $^\circ\text{C}$ |
| T_{JM} | | 150 | $^\circ\text{C}$ |
| T_{stg} | | -55 ... +150 | $^\circ\text{C}$ |
| T_L | 1.6 mm (0.062 in.) from case for 10 s | 300 | $^\circ\text{C}$ |
| M_d | Mounting torque | 1.13/10 | Nm/lb.in. |
| Weight | | TO-204 = 18 g, TO-247 = 6 g | |

TO-247 AD (IXFH)



~~TO-204 AA (IXFM)~~

Package
unavailable



G = Gate, D = Drain, S = Source, TAB = Drain

Features

- International standard packages
- Low $R_{DS(on)}$ HDMOS™ process
- Rugged polysilicon gate cell structure
- Unclamped Inductive Switching (UIS) rated
- Low package inductance
 - easy to drive and to protect
- Fast intrinsic Rectifier

Applications

- DC-DC converters
- Synchronous rectification
- Battery chargers
- Switched-mode and resonant-mode power supplies
- DC choppers
- AC motor control
- Temperature and lighting controls
- Low voltage relays

Advantages

- Easy to mount with 1 screw (TO-247) (isolated mounting screw hole)
- Space savings
- High power density

| Symbol | Test Conditions | Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified) | | |
|--|---|---|------|-------------------|
| | | min. | typ. | max. |
| V_{DSS} | $V_{GS} = 0$ V, $I_D = 3$ mA | 1000 | | V |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = 4$ mA | 2.0 | | V |
| I_{GSS} | $V_{GS} = \pm 20$ V $_{DC}$, $V_{DS} = 0$ | | | ± 100 nA |
| I_{DSS} | $V_{DS} = 0.8 \cdot V_{DSS}$, $V_{GS} = 0$ V | $T_J = 25^\circ\text{C}$ | | 250 μA |
| | | $T_J = 125^\circ\text{C}$ | | 1 mA |
| $R_{DS(on)}$ | $V_{GS} = 10$ V, $I_D = 0.5 \cdot I_{D25}$ | 10N100 | | 1.20 Ω |
| | | 12N100 | | 1.05 Ω |
| | | 13N100 | | 0.90 Ω |
| Pulse test, $t \leq 300$ μs , duty cycle $d \leq 2\%$ | | | | |

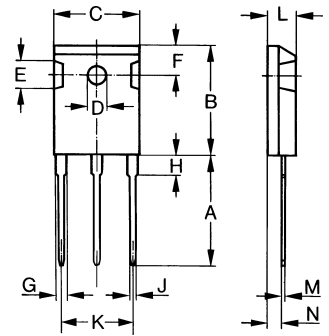
IXYS reserves the right to change limits, test conditions, and dimensions.

91531F(4/99)

| Symbol | Test Conditions | Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified) | | | |
|--------------|--|---|------|------|----|
| | | min. | typ. | max. | |
| g_{fs} | $V_{DS} = 10\text{ V}; I_D = 0.5 \cdot I_{D25}$, pulse test | 6 | 10 | S | |
| C_{iss} | $V_{GS} = 0\text{ V}, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$ | | 4000 | pF | |
| C_{oss} | | | 310 | pF | |
| C_{rss} | | | 70 | pF | |
| $t_{d(on)}$ | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$ $R_G = 2\ \Omega$ (External), | | 21 | 50 | ns |
| t_r | | | 33 | 50 | ns |
| $t_{d(off)}$ | | | 62 | 100 | ns |
| t_f | | | 32 | 50 | ns |
| $Q_{g(on)}$ | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$ | | 122 | 155 | nC |
| Q_{gs} | | | 30 | 45 | nC |
| Q_{gd} | | | 50 | 80 | nC |
| R_{thJC} | | | 0.42 | K/W | |
| R_{thCK} | | 0.25 | | K/W | |

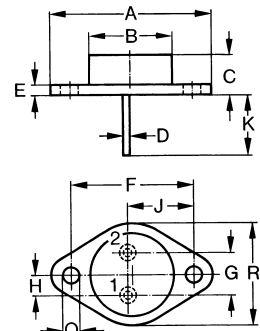
| Symbol | Test Conditions | Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified) | | |
|----------|---|---|------|------------------------|
| | | min. | typ. | max. |
| I_S | $V_{GS} = 0\text{ V}$ | 10N100 12N100 13N100 | | 10 A 12 A 12.5 A |
| I_{SM} | Repetitive; pulse width limited by T_{JM} | 10N100 12N100 13N100 | | 40 A 48 A 50 A |
| V_{SD} | $I_F = I_S, V_{GS} = 0\text{ V}$, Pulse test, $t \leq 300\ \mu\text{s}$, duty cycle $d \leq 2\%$ | | | 1.5 V |
| t_{rr} | $I_F = I_S$ $-di/dt = 100\text{ A}/\mu\text{s}$, $V_R = 100\text{ V}$ | $T_J = 25^\circ\text{C}$ | | 250 ns |
| | | $T_J = 125^\circ\text{C}$ | | 400 ns |
| Q_{RM} | | $T_J = 25^\circ\text{C}$ | 1 | μC |
| | | $T_J = 125^\circ\text{C}$ | 2 | μC |
| I_{RM} | | $T_J = 25^\circ\text{C}$ | 10 | A |
| | | $T_J = 125^\circ\text{C}$ | 15 | A |

TO-247 AD (IXFH) Outline



| Dim. | Millimeter | | Inches | |
|------|------------|-------|--------|-------|
| | Min. | Max. | Min. | Max. |
| A | 19.81 | 20.32 | 0.780 | 0.800 |
| B | 20.80 | 21.46 | 0.819 | 0.845 |
| C | 15.75 | 16.26 | 0.610 | 0.640 |
| D | 3.55 | 3.65 | 0.140 | 0.144 |
| E | 4.32 | 5.49 | 0.170 | 0.216 |
| F | 5.4 | 6.2 | 0.212 | 0.244 |
| G | 1.65 | 2.13 | 0.065 | 0.084 |
| H | - | 4.5 | - | 0.177 |
| J | 1.0 | 1.4 | 0.040 | 0.055 |
| K | 10.8 | 11.0 | 0.426 | 0.433 |
| L | 4.7 | 5.3 | 0.185 | 0.209 |
| M | 0.4 | 0.8 | 0.016 | 0.031 |
| N | 1.5 | 2.49 | 0.087 | 0.102 |

TO-204 AA (IXFM) Outline



| Dim. | Millimeter | | Inches | |
|------|------------|-------|--------|-------|
| | Min. | Max. | Min. | Max. |
| A | 38.61 | 39.12 | 1.520 | 1.540 |
| B | 19.43 | 19.94 | - | 0.785 |
| C | 6.40 | 9.14 | 0.252 | 0.360 |
| D | 0.97 | 1.09 | 0.038 | 0.043 |
| E | 1.53 | 2.92 | 0.060 | 0.115 |
| F | 30.15 | BSC | 1.187 | BSC |
| G | 10.67 | 11.17 | 0.420 | 0.440 |
| H | 5.21 | 5.71 | 0.205 | 0.225 |
| J | 16.64 | 17.14 | 0.655 | 0.675 |
| K | 11.18 | 12.19 | 0.440 | 0.480 |
| Q | 3.84 | 4.19 | 0.151 | 0.165 |
| R | 25.16 | 25.90 | 0.991 | 1.020 |

Fig. 1 Output Characteristics

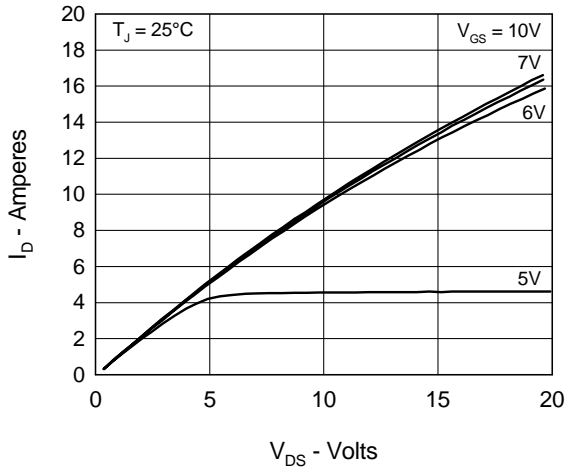


Fig. 2 Input Admittance

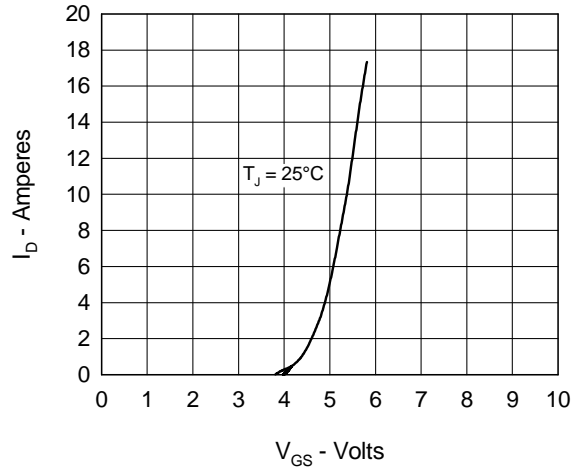


Fig. 3 $R_{DS(on)}$ vs. Drain Current

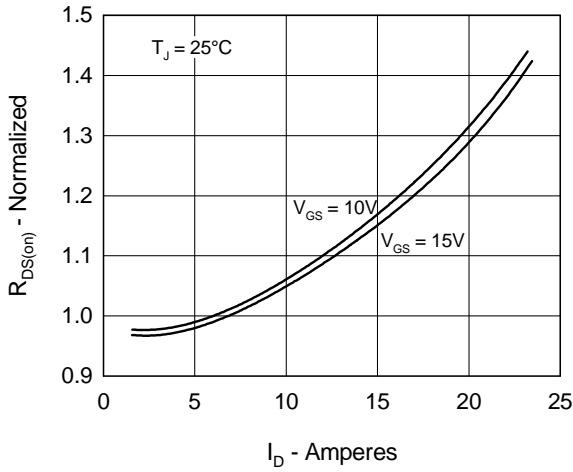


Fig. 4 Temperature Dependence of Drain to Source Resistance

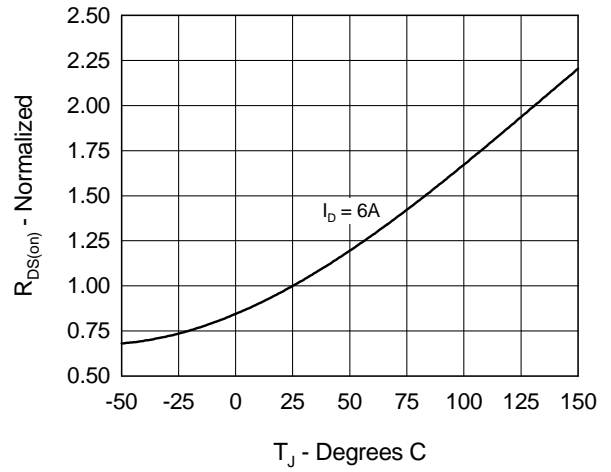


Fig. 5 Drain Current vs. Case Temperature

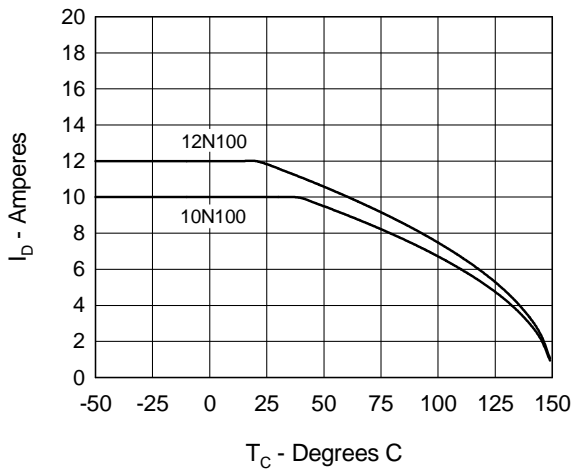


Fig. 6 Temperature Dependence of Breakdown and Threshold Voltage

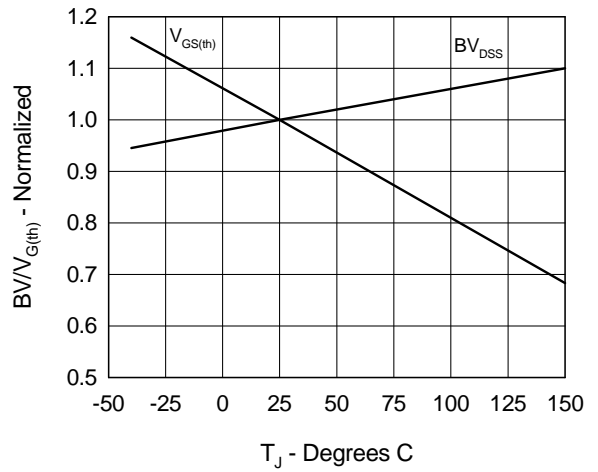


Fig.7 Gate Charge Characteristic Curve

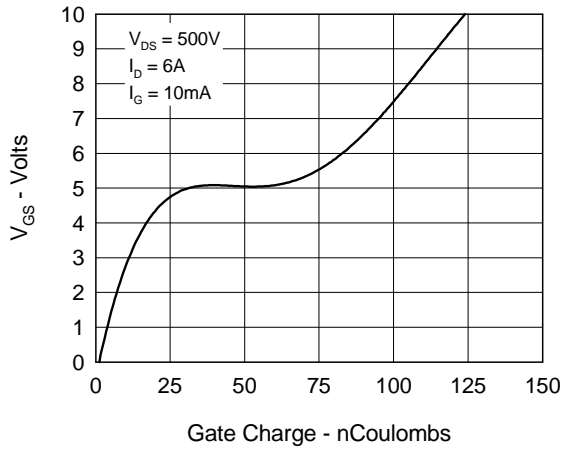


Fig.8 Capacitance Curves

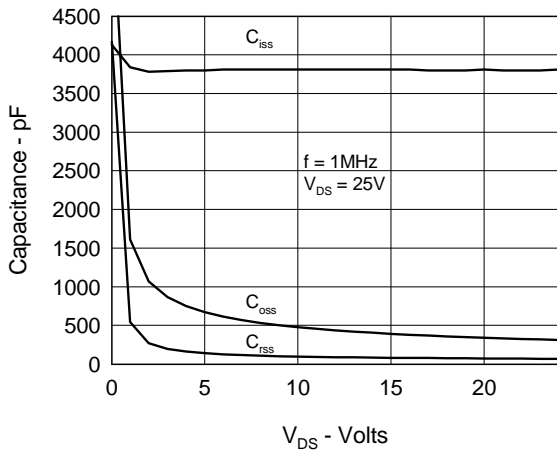


Fig.9 Source Current vs. Source to Drain Voltage

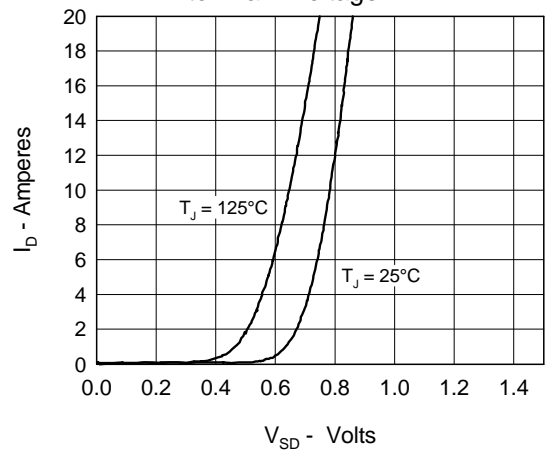
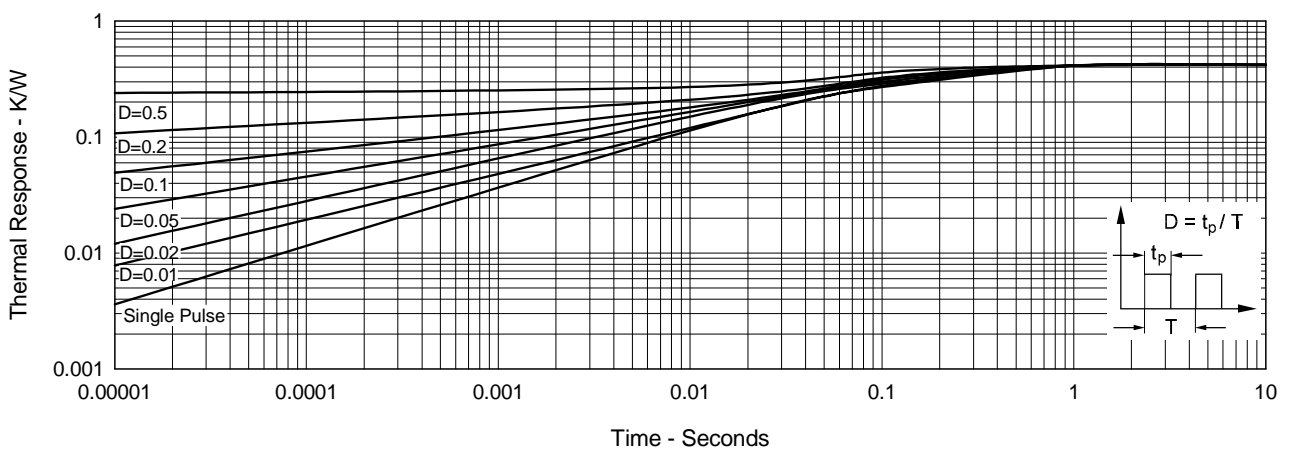


Fig.10 Transient Thermal Impedance





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